## IN THE CLAIMS:

Please amend the claims as follows:

- 1. (Currently Amended) A method of electrochemically and mechanically planarizing a surface of a substrate, comprising:
- (a) providing a basin containing an electrically conductive solution and an electrode disposed therein in contact with the electrically conductive solution;
- (b) disposing a polishing medium in <u>contact with</u> the electrically conductive solution;
- (c) positioning a substrate <u>having a conductive material formed thereon</u> against the polishing medium so that a surface of the substrate contacts the electrically conductive solution and the polishing medium;
- (d) applying a first <u>positive</u> potential between the polishing medium and the electrode for a first time period <u>to remove conductive material from the substrate</u>; and
- (e) applying a second <u>positive</u> potential between the polishing medium and the electrode for a second time period <u>to remove conductive material from the substrate</u>, wherein the second potential is lower than the first potential.
- 2. (Currently Amended) The method of claim 1, wherein the second potential is a zero potential the polishing medium comprises an electrode.
- 3. (Currently Amended) The method of claim 1, wherein the second potential is lower than the first positive potential is between about 4 volts and about 8 volts, and the second positive potential is between about 0.5 volts and about 4 volts.
- 4. (Currently Amended) The method of claim 1, wherein the first <u>positive</u> potential is a pulsed potential with a waveform.
- 5. (Currently Amended) The method of claim 1, wherein the first <u>positive</u> potential is a pulsed potential with a waveform and the second <u>positive</u> potential is a pulsed potential with a waveform.

- 6. (Currently Amended) The method of claim 1, wherein the first potential is a pulsed potential with a waveform and the second potential is a pulsed potential with a waveform and a negative polarity further comprising providing relative motion between the substrate and the polishing medium.
- 7. (Currently Amended) The method of claim 1, wherein the first potential is a pulsed potential with a waveform and the second potential is a zero potential the polishing medium comprises a conductive portion, and the conductive portion comprises an electrode.
- 8. (Currently Amended) The method of claim 1, wherein the first <u>positive</u> potential is modulated within a predefined range of potentials.
- 9. (Currently Amended) The method of claim 1, wherein the second <u>positive</u> potential is modulated within a predefined range of potentials.
- 10. (Original) The method of claim 1, further comprising repeating steps (d) and (e) for a third time period.
- 11. (Currently Amended) The method of claim 1, wherein applying the first potential comprises: applying a third potential between the polishing medium and the electrode for a third time period; and

applying a fourth potential between the polishing medium and the electrode for a fourth time period the polishing medium comprises a conductive polishing material or a composite of a conductive polishing material disposed in a conventional polishing material.

12. (Currently Amended) The method of claim 11, wherein the third potential is a pulsed potential with a waveform and the fourth potential is a pulsed potential with a waveform conductive material comprises copper or tungsten.

13. (Currently Amended) The method of claim 1, wherein applying the second potential comprises:

applying a third potential between the polishing medium and the electrode for a third time period; and

applying a fourth potential between the polishing medium and the electrode for a fourth time period further comprising applying a third potential between the polishing medium and the electrode for a third time period, and the third potential is a zero potential.

- 14. (Currently Amended) The method of claim [13] 16, wherein the third potential is a pulsed potential with a waveform and the fourth potential is a pulsed potential with a waveform the third positive potential is between about 4 volts and about 8 volts.
- 15. (Original) The method of claim 1, wherein the first time period is greater than the second time period.
- 16. (Currently Amended) The method of claim 1, further comprising applying a third <u>positive</u> potential between the polishing medium and the electrode for a third time period.
- 17. (Currently Amended) The method of claim 16, wherein the third <u>positive</u> potential is a pulsed potential with a waveform.
- 18. (Currently Amended) The method of claim 16, wherein the first <u>positive</u> potential is a pulsed potential with a waveform, the second <u>positive</u> potential is a pulsed potential with a waveform, and the third <u>positive</u> potential is a pulsed potential with a waveform.
- 19. (Currently Amended) The method of claim 1, further comprising

(f) applying a third <u>positive or zero</u> potential between the polishing medium and the electrode for a third time period; and

repeating steps (d) through (f) for a period of time.